Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	76	(SiGe or GeSi or (Si near1 Ge) or (germ?nium near1 silicon)) near12 ((elevated raised) near2 (source drain "source/drain"))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 13:32
L2	24	1 and ((salicid$3 silicid$3) near12 (nickel Ni))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 13:32
L3	24	1 and ((salicid$3 silicid$3 monosilicide) near12 (nickel Ni))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 15:36
L4	1	3 and @ad<"20000306"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 13:33
L5	599	(SiGe or GeSi or (Si near1 Ge) or (germ?nium near1 silicon)) near12 (silicid$3 salicid$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 14:47
L6	128	5 and ((salicid$3 silicid$3) near12 (nickel Ni))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 13:32
L7	0	3 and @rlad<"20000306"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 13:33
L8	32	6 and @ad<"20000306"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 13:33
L9	15	6 and @rlad<"20000306"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 13:33

L10	33	8 9	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 14:08
L11	4	"6753606"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 14:46
L12	25	(("5,510,295") or ("5,608,226") or ("5,624,869") or ("5,828,131") or ("5,830,775") or ("5,710,450") or ("6,121,100") or ("6,165,826") or ("6,211,560") or ("6,326,664") or ("4965645") or ("5336903") or ("5401674")).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/12/11 14:47
L13	11	(SiGe or GeSi or (Si near1 Ge) or (germ?nium near1 silicon)) and 12	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 14:58
L14	1	13 and (ni nickel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 14:58
L15	129	resistivity near12 ((salicid$3 silicid$3 monosilicide) near12 (nickel Ni))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 15:53
L16	3	15 and (international adj business).asn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 15:37
L17	6	resistivity near12 (monosilicide near3 (nickel Ni))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 15:55
L18	64	resistivity near12 NiSi	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 15:59
L19	21	resistivity near12 "NiSi.sub.2"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 15:56

L20	3	resistivity near12 ("Ni.sub.2Si" or "Ni.sub.2 ad Si")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 15:57
L21	74	18 19 20	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 15:57
L22	12	18 and 19	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/11 15:57